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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)	Complete if Known		
	Application Number	Unknown	
	Filing Date	Even Date Herewith	
	First Named Inventor	Ahn, Kie	
	Group Art Unit	Unknown	
	Examiner Name	Unknown	
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Substitute for form 1449APTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)	Complete if Known			
	<b>Application Number</b>	Unknown		
	Filing Date	Even Date Herewith		
	First Named Inventor	Ahn, Kie		
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	Examiner Name	Unknown		
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